

No.1312B

NPN Epitaxial Planar Silicon Transistor

CRT Horizontal Deflection Output Applications (with Damper Diode)

## **Features**

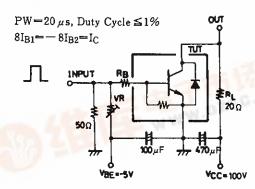
- · Fast switching speed.
- · Especially suited for use in high-definition CRT display ( $V_{CC} = 12 \text{ to } 24V$ ).

WWW.DZSC.COM

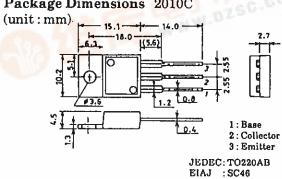
· Wide ASO.

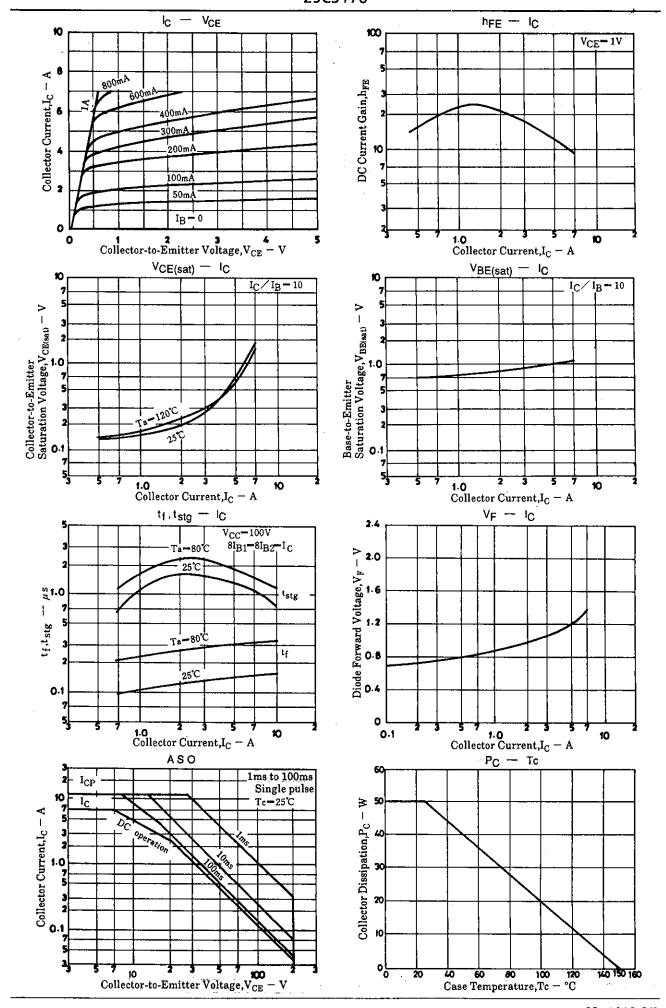
Absolute Maximum Ratings at Ta = 25°C unit						
Collector-to-Base Voltage				400	unit	i.
Collector-to-Emitter Voltage	V <sub>CBO</sub>			400	V	
	V <sub>CEO</sub>			200	V	
Emitter-to-Base Voltage	$V_{EBO}$			6	V	
Collector Current	$I_{\mathbf{C}}$			7	A	
Collector Current (Pulse)	$I_{CP}$			12	A	
Base Current	$I_B$			4	A	
Collector Dissipation	$P_{\mathbf{C}}$	Tc=25°C		50	W	
Junction Temperature	Tj			150	°C	
Storage Temperature	Tstg		-55 to +		°C	
-					Ū	
Electrical Characteristics at Ta = 25°C			min	typ	max	unit
Collector Cutoff Current	I <sub>CBO</sub>	$V_{CB} = 200V, I_E = 0$		-J F	100	μΑ
Emitter Cutoff Current		$V_{EB} = 6V, I_C = 0$			400	mA
DC Current Gain		$V_{CE} = 1V, I_{C} = 1A$	15		100	
		$V_{CE} = 1V, I_C = 5A$	8		40	
Gain-Bandwidth Product	f <sub>T</sub>	$V_{CE} = 10V, I_C = 0.5A$	10	40	70	MHz
C-E Saturation Voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 5A, I_{\rm B} = 0.65A$	10	40		V
B-E Saturation Voltage	VDE(sat)	$I_C = 5A, I_B = 0.65A$			10	
C-B Breakdown Voltage	$V_{BE(sat)}$		400		1.3	V
		$I_C = 1 \text{mA}, I_E = 0$	400			V
Diode Forward Voltage	$V_{\mathbf{F}}$	$I_F = 5A$			. 1.5	V
Fall Time	tf	$I_C = 5A$ , $I_{B1} = -I_{B2} = 0.625A$			0.5	μs

## Switching Time Test Circuit



## Package Dimensions 2010C





- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
  - Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
  - 2 Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of September, 1996. Specifications and information herein are subject to change without notice.